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APPLICATION NO.	FILI	NG DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/530,063	03/	/31/2005	Philippe Meunier-Beillard	BE02 0027 US 6267	
65913 NXP, B.V.	7590	07/02/2007		EXAMINER	
NXP INTEL	LECTUAL	PROPERTY DEPA	ESTRADA,	ESTRADA, MICHELLE	
M/S41-SJ 1109 MCKA	Y DRIVE			ART UNIT	PAPER NUMBER
SAN JOSE, O	CA 95131			2823	
				NOTIFICATION DATE	DELIVERY MODE
•				07/02/2007	ELECTRONIC

# Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Notice of the Office communication was sent electronically on above-indicated "Notification Date" to the following e-mail address(es):

ip.department.us@nxp.com

			A 11 (/ )	
		Application No.	Applicant(s)	
		10/530,063	MEUNIER-BEILLARD ET AL.	
Office Action Sum	mary	Examiner	Art Unit	
		Michelle Estrada	2823	
The MAILING DATE of this Period for Reply	communication app	ears on the cover sheet with the c	orrespondence address	
A SHORTENED STATUTORY P WHICHEVER IS LONGER, FRO - Extensions of time may be available under t after SIX (6) MONTHS from the mailing date - If NO period for reply is specified above, the - Failure to reply within the set or extended pr	M THE MAILING DA he provisions of 37 CFR 1.13 e of this communication. maximum statutory period veriod for reply will, by statute, hree months after the mailing	Y IS SET TO EXPIRE 3 MONTH(ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be time will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONED date of this communication, even if timely filed	I. lely filed the mailing date of this communication. C (35 U.S.C. § 133).	
Status				
1) Responsive to communica	tion(s) filed on <u>14 Ju</u>	ine 2007.		
2a) This action is <b>FINAL</b> .	2b)⊠ This	action is non-final.		
3) Since this application is in	condition for allowar	nce except for formal matters, pro	secution as to the merits is	
closed in accordance with	the practice under E	x parte Quayle, 1935 C.D. 11, 45	i3 O.G. 213.	
Disposition of Claims				
4) ⊠ Claim(s) <u>1-8 and 17-20</u> is/a 4a) Of the above claim(s) _ 5) □ Claim(s) is/are allov 6) ⊠ Claim(s) <u>1-3,6-8 and 20</u> is/ 7) ⊠ Claim(s) <u>4,5,18 and 19</u> is/a 8) □ Claim(s) are subjec	is/are withdrav ved. are rejected. are objected to.	vn from consideration.		
Application Papers				
• • • • • • • • • • • • • • • • • • • •	is/are: a) ☐ acce at any objection to the b) including the correct	epted or b) objected to by the Eddrawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).	
Priority under 35 U.S.C. § 119				
12) Acknowledgment is made of a) All b) Some * c) N  1. Certified copies of the 2. Certified copies of the 3. Copies of the certified application from the	lone of: te priority documents te priority documents td copies of the prior International Bureau	priority under 35 U.S.C. § 119(a) is have been received. In Application in Applic	on No ed in this National Stage	
Attachment(s)			(DTO 442)	
<ol> <li>Notice of References Cited (PTO-892)</li> <li>Notice of Draftsperson's Patent Drawin</li> </ol>	g Review (PTO-948)	4) Interview Summary Paper No(s)/Mail Da		
Information Disclosure Statement(s) (P Paper No(s)/Mail Date	-	5) Notice of Informal P 6) Other:		

### **DETAILED ACTION**

#### Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 6/14/07 has been entered.

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1-3 and 6 are rejected under 35 U.S.C. 102(b) as being anticipated by Coleman (5,155,062).

Re claim 1, Coleman discloses depositing an epitaxial layer based on Group IV elements, silicon carbide, on a silicon substrate by Chemical Vapor Deposition using source gases (See abstract), and including employing nitrogen as a carrier gas (Col. 1, lines 35-45).

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Re claim 2, Coleman discloses forming an epitaxial layer based on at least one of the following silicon and carbon.

Re claim 3, Coleman discloses wherein the epitaxial layer comprises Si<sub>1-y</sub>C<sub>y</sub>.

Re claim 6, Coleman discloses wherein the epitaxial layer comprises a silicon epitaxial layer.

Claims 1, 3 and 6 are rejected under 35 U.S.C. 102(b) as being anticipated by Kong et al. (5,119,540).

Re claim 1, Kong et al. disclose depositing an epitaxial layer based on Group IV elements, silicon carbide, on a silicon substrate by Chemical Vapor Deposition using source gases, and including employing nitrogen as a carrier gas (Col. 3, lines 17-22).

Re claim 3, Kong et al. disclose wherein the epitaxial layer comprises Si<sub>1-y</sub>C<sub>y</sub>.

Re claim 6, Kong et al. disclose wherein the epitaxial layer comprises a silicon epitaxial layer.

# Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

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Claims 7, 8, 17 and 20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Coleman as applied to claims 1-3 and 6 above, and further in view of the following comments.

Coleman does not disclose a particular temperature range of the CVD process.

One of ordinary skill in the art would have been led to the recited CVD temperature through routine experimentation to achieve a desired rate of deposition and layer associated characteristics. In addition, the selection of the CVD temperature, its obvious because it is a matter of determining optimum process conditions by routine experimentation with a limited number of species of result effective variables. These claims are prima facie obvious without showing that the claimed ranges achieve unexpected results relative to the prior art range. In re Woodruff, 16 USPQ2d 1935, 1937 (Fed. Cir. 1990). See also In re Huang, 40 USPQ2d 1685, 1688 (Fed. Cir. 1996)(claimed ranges or a result effective variable, which do not overlap the prior art ranges, are unpatentable unless they produce a new and unexpected result which is different in kind and not merely in degree from the results of the prior art). See also In re Boesch, 205 USPQ 215 (CCPA) (discovery of optimum value of result effective variable in known process is ordinarily within skill or art) and In re Aller, 105 USPQ 233 (CCPA 1995) (selection of optimum ranges within prior art general conditions is obvious).

Note that the specification contains no disclosure of either the critical nature of the claimed CVD temperature or any unexpected results arising therefrom. Where patentability is said to be based upon particular chosen CVD temperature or upon Art Unit: 2823

another variable recited in a claim, the Applicant must show that the chosen CVD temperature are critical. *In re Woodruf*, 919 F.2d 1575, 1578, 16 USPQ2d 1934, 1936 (Fed. Cir. 1990).

### Allowable Subject Matter

Claims 4, 5, 18 and 18 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

## Response to Arguments

Applicant's arguments filed 4/25/07 have been fully considered but they are not persuasive. Applicant argues that Coleman does not teach using nitrogen as the actual carrier gas for a source gas used in a CVD process; and that the mere presence of nitrogen in a source or carrier gas does not teach employing nitrogen as a carrier gas for a CVD process as in the claimed invention. However, the mere presence of nitrogen in a source or carrier gas does teach employing nitrogen as a carrier gas for a CVD process. The process suggested by Coleman is encompassed by the instant claims.

Applicant argues that Coleman discloses undesirable nitrogen that can be present in CVD-grown epitaxial layers and, source or carrier gases does not teach using nitrogen as a carrier gas. However, the additional teachings of the reference does not render invalid the teachings relied on.

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#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Michelle Estrada whose telephone number is 571-272-1858. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew Smith can be reached on 571-272-1907. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 571-272-2800.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Michelle Estrada Primary Examiner Art Unit 2823